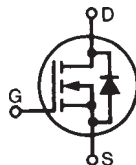


### GigaMOS™ Power MOSFET

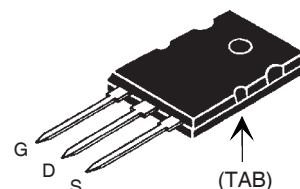
### IXFK120N30T IXFX120N30T

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode

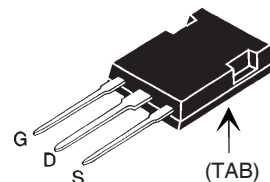


$$\begin{aligned} V_{DSS} &= 300V \\ I_{D25} &= 120A \\ R_{DS(on)} &\leq 24m\Omega \\ t_{rr} &\leq 200ns \end{aligned}$$

TO-264 (IXFK)



PLUS247 (IXFX)



G = Gate      D = Drain  
S = Source      TAB = Drain

| Symbol        | Test Conditions                                                          | Maximum Ratings   |                  |
|---------------|--------------------------------------------------------------------------|-------------------|------------------|
| $V_{DSS}$     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                          | 300               | V                |
| $V_{DGR}$     | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GS} = 1M\Omega$    | 300               | V                |
| $V_{GSS}$     | Continuous                                                               | $\pm 20$          | V                |
| $V_{GSM}$     | Transient                                                                | $\pm 30$          | V                |
| $I_{D25}$     | $T_C = 25^\circ\text{C}$                                                 | 120               | A                |
| $I_{DM}$      | $T_C = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$               | 330               | A                |
| $I_A$         | $T_C = 25^\circ\text{C}$                                                 | 30                | A                |
| $E_{AS}$      | $T_C = 25^\circ\text{C}$                                                 | 2.5               | J                |
| $dV/dt$       | $I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$ | 20                | V/ns             |
| $P_D$         | $T_C = 25^\circ\text{C}$                                                 | 960               | W                |
| $T_J$         |                                                                          | -55 ... +150      | $^\circ\text{C}$ |
| $T_{JM}$      |                                                                          | 150               | $^\circ\text{C}$ |
| $T_{stg}$     |                                                                          | -55 ... +150      | $^\circ\text{C}$ |
| $T_L$         | 1.6mm (0.062 in.) from Case for 10s                                      | 300               | $^\circ\text{C}$ |
| $T_{SOLD}$    | Plastic Body for 10s                                                     | 260               | $^\circ\text{C}$ |
| $M_d$         | Mounting Torque (TO-264)                                                 | 1.13/10           | Nm/lb.in.        |
| $F_C$         | Mounting Force (PLUS247)                                                 | 20..120 / 4.5..27 | N/lb.            |
| <b>Weight</b> | TO-264                                                                   | 10                | g                |
|               | PLUS247                                                                  | 6                 | g                |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) | Characteristic Values |      |                          |
|--------------|---------------------------------------------------------------------------|-----------------------|------|--------------------------|
|              |                                                                           | Min.                  | Typ. | Max.                     |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 3mA$                                               | 300                   |      | V                        |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 4mA$                                           | 2.5                   |      | 5.0 V                    |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                        |                       |      | $\pm 200$ nA             |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 125^\circ\text{C}$           |                       |      | 50 $\mu\text{A}$<br>3 mA |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 60A$ , Note 1                                     |                       |      | 24 m $\Omega$            |

#### Features

- International Standard Packages
- High Current Handling Capability
- Fast Intrinsic Diode
- Avalanche Rated
- Low  $R_{DS(on)}$

#### Advantages

- Easy to Mount
- Space Savings
- High Power Density

#### Applications

- DC-DC Converters
- Battery Chargers
- Switched-Mode and Resonant-Mode Power Supplies
- DC Choppers
- AC Motor Drives
- Uninterruptible Power Supplies
- High Speed Power Switching Applications

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                                                                          | Characteristic Values |      |                    |
|--------------|----------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------|--------------------|
|              |                                                                                                                                                    | Min.                  | Typ. | Max.               |
| $g_{fs}$     | $V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1                                                                                                | 70                    | 120  | S                  |
| $C_{iss}$    | $V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$                                                                                   |                       | 20   | nF                 |
| $C_{oss}$    |                                                                                                                                                    |                       | 1380 | pF                 |
| $C_{rss}$    |                                                                                                                                                    |                       | 135  | pF                 |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 15\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$<br>$R_G = 1\Omega$ (External) |                       | 32   | ns                 |
| $t_r$        |                                                                                                                                                    |                       | 31   | ns                 |
| $t_{d(off)}$ |                                                                                                                                                    |                       | 87   | ns                 |
| $t_f$        |                                                                                                                                                    |                       | 23   | ns                 |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$                                                                   |                       | 265  | nC                 |
| $Q_{gs}$     |                                                                                                                                                    |                       | 87   | nC                 |
| $Q_{gd}$     |                                                                                                                                                    |                       | 60   | nC                 |
| $R_{thJC}$   |                                                                                                                                                    |                       | 0.13 | $^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                                    | 0.15                  |      | $^\circ\text{C/W}$ |

## Source-Drain Diode

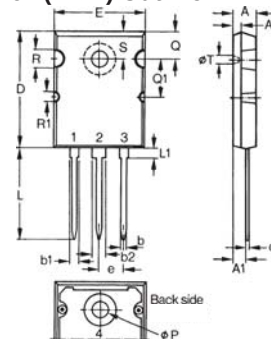
| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)                          | Characteristic Values |      |               |
|----------|------------------------------------------------------------------------------------------------------|-----------------------|------|---------------|
|          |                                                                                                      | Min.                  | Typ. | Max.          |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                                 |                       |      | 120 A         |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$                                                          |                       |      | 480 A         |
| $V_{SD}$ | $I_F = 60\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1                                                   |                       |      | 1.5 V         |
| $t_{rr}$ | $I_F = 60\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 75\text{V}$ , $V_{GS} = 0\text{V}$ |                       | 0.8  | ns            |
| $Q_{RM}$ |                                                                                                      |                       | 10.4 | $\mu\text{C}$ |
| $I_{RM}$ |                                                                                                      |                       |      | A             |

Note 1: Pulse Test,  $t \leq 300\mu\text{s}$ ; Duty Cycle,  $d \leq 2\%$ .

## ADVANCE TECHNICAL INFORMATION

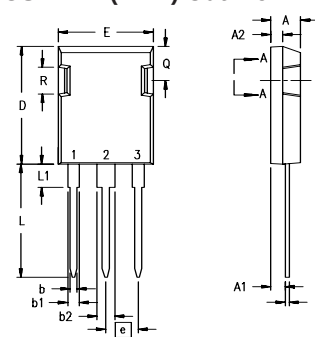
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

## TO-264 (IXFK) Outline



| Dim. | Millimeter |       | Inches   |       |
|------|------------|-------|----------|-------|
|      | Min.       | Max.  | Min.     | Max.  |
| A    | 4.82       | 5.13  | .190     | .202  |
| A1   | 2.54       | 2.89  | .100     | .114  |
| A2   | 2.00       | 2.10  | .079     | .083  |
| b    | 1.12       | 1.42  | .044     | .056  |
| b1   | 2.39       | 2.69  | .094     | .106  |
| b2   | 2.90       | 3.09  | .114     | .122  |
| c    | 0.53       | 0.83  | .021     | .033  |
| D    | 25.91      | 26.16 | 1.020    | 1.030 |
| E    | 19.81      | 19.96 | .780     | .786  |
| e    | 5.46 BSC   |       | .215 BSC |       |
| J    | 0.00       | 0.25  | .000     | .010  |
| K    | 0.00       | 0.25  | .000     | .010  |
| L    | 20.32      | 20.83 | .800     | .820  |
| L1   | 2.29       | 2.59  | .090     | .102  |
| P    | 3.17       | 3.66  | .125     | .144  |
| Q    | 6.07       | 6.27  | .239     | .247  |
| Q1   | 8.38       | 8.69  | .330     | .342  |
| R    | 3.81       | 4.32  | .150     | .170  |
| R1   | 1.78       | 2.29  | .070     | .090  |
| S    | 6.04       | 6.30  | .238     | .248  |
| T    | 1.57       | 1.83  | .062     | .072  |

## PLUS 247™ (IXFX) Outline



Terminals: 1 - Gate  
2 - Drain (Collector)  
3 - Source (Emitter)  
4 - Drain (Collector)

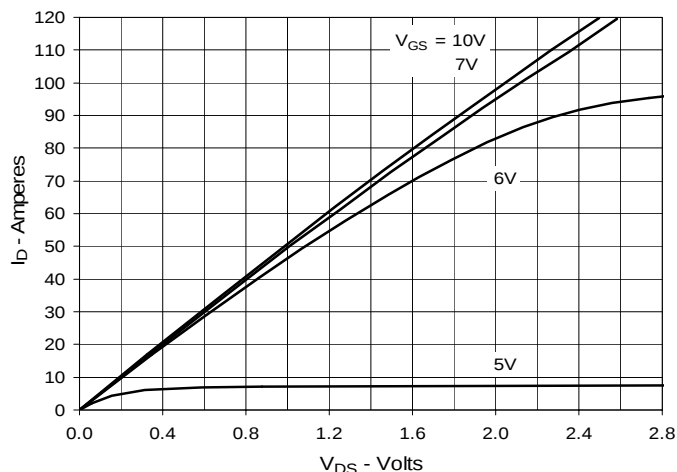
| Dim. | Millimeter |       | Inches   |      |
|------|------------|-------|----------|------|
|      | Min.       | Max.  | Min.     | Max. |
| A    | 4.83       | 5.21  | .190     | .205 |
| A1   | 2.29       | 2.54  | .090     | .100 |
| A2   | 1.91       | 2.16  | .075     | .085 |
| b    | 1.14       | 1.40  | .045     | .055 |
| b1   | 1.91       | 2.13  | .075     | .084 |
| b2   | 2.92       | 3.12  | .115     | .123 |
| C    | 0.61       | 0.80  | .024     | .031 |
| D    | 20.80      | 21.34 | .819     | .840 |
| E    | 15.75      | 16.13 | .620     | .635 |
| e    | 5.45 BSC   |       | .215 BSC |      |
| L    | 19.81      | 20.32 | .780     | .800 |
| L1   | 3.81       | 4.32  | .150     | .170 |
| Q    | 5.59       | 6.20  | .220     | .244 |
| R    | 4.32       | 4.83  | .170     | .190 |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

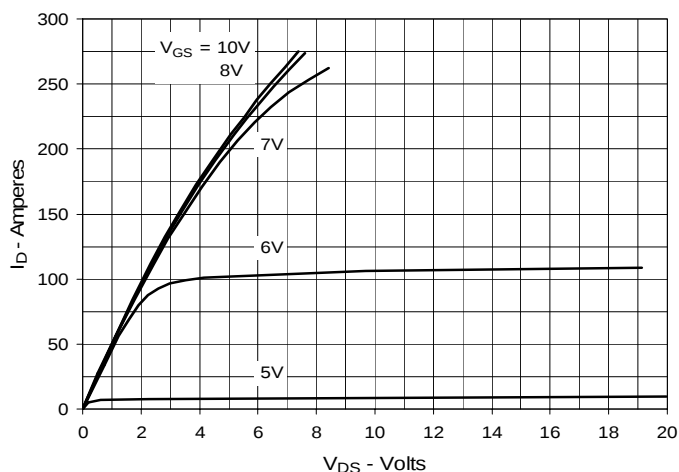
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |              |             |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

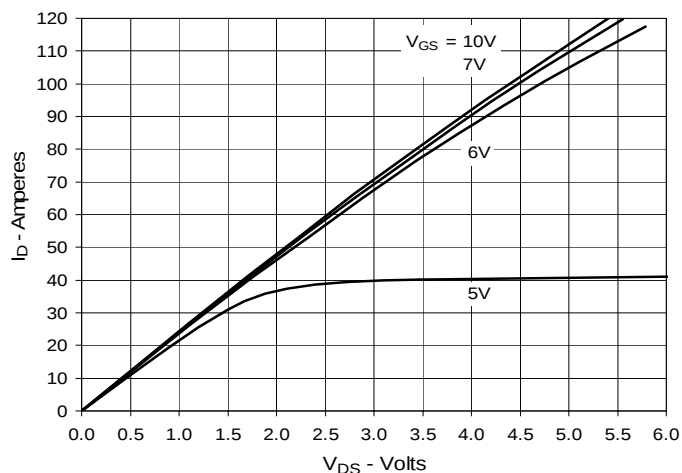
**Fig. 1. Output Characteristics**  
@ 25°C



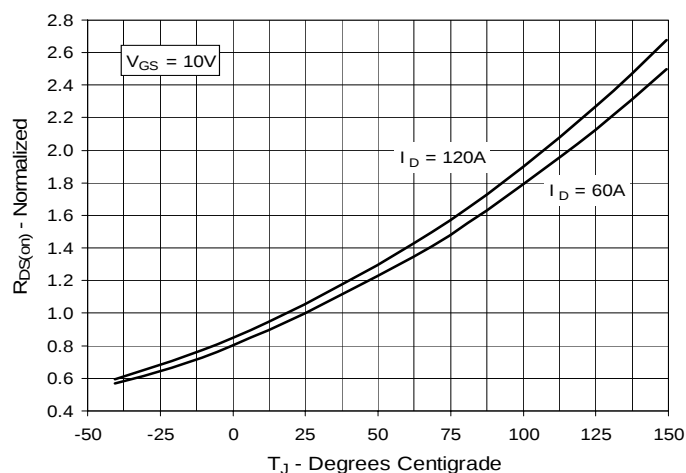
**Fig. 2. Extended Output Characteristics**  
@ 25°C



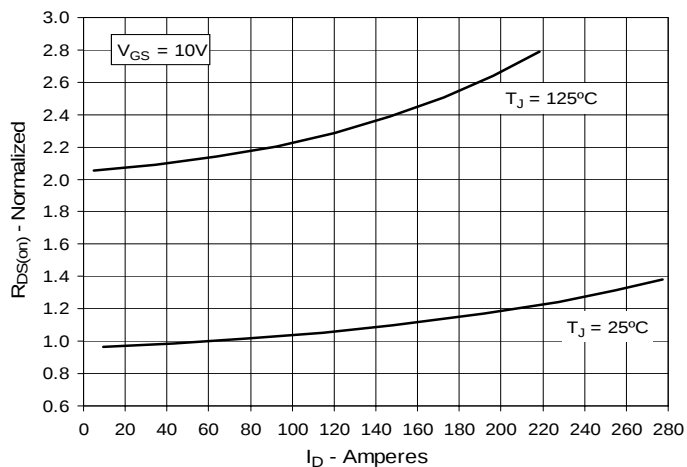
**Fig. 3. Output Characteristics**  
@ 125°C



**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 60A$  Value**  
vs. Junction Temperature



**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 60A$  Value**  
vs. Drain Current



**Fig. 6. Maximum Drain Current vs.**  
Case Temperature

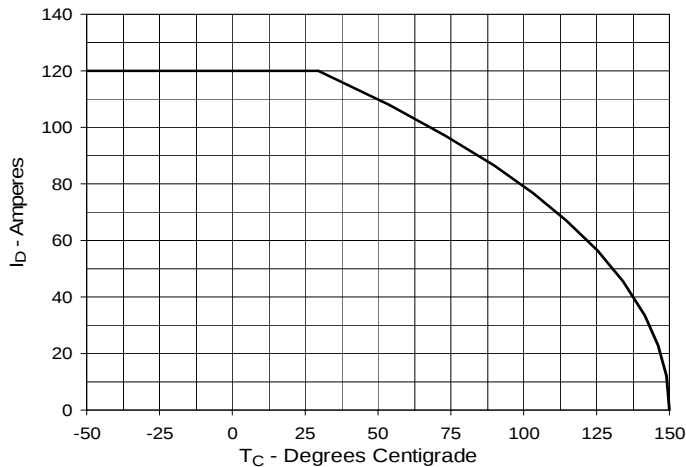


Fig. 7. Input Admittance

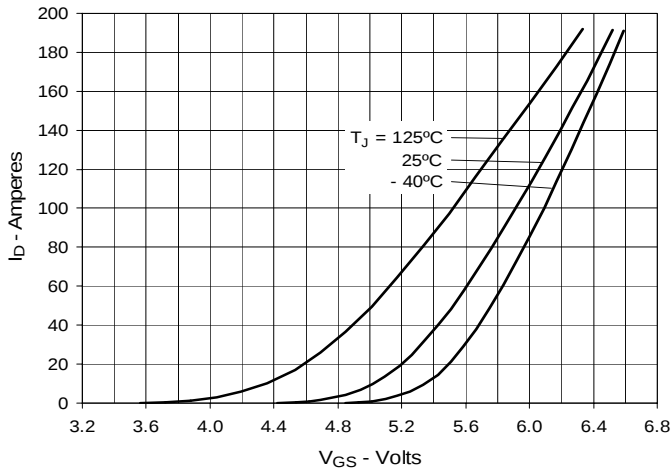


Fig. 8. Transconductance

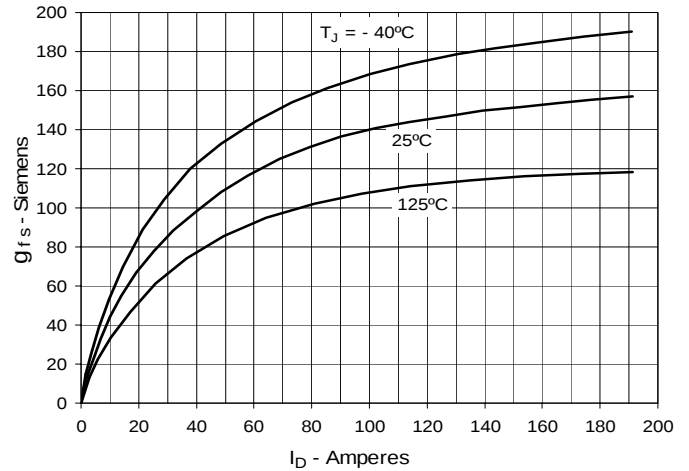


Fig. 9. Forward Voltage Drop of Intrinsic Diode

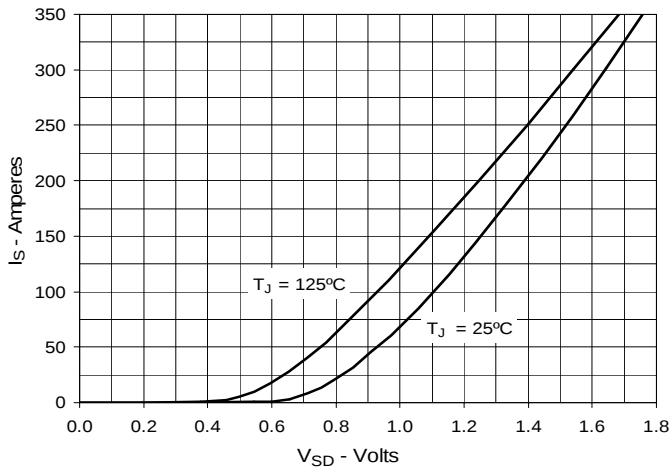


Fig. 10. Gate Charge

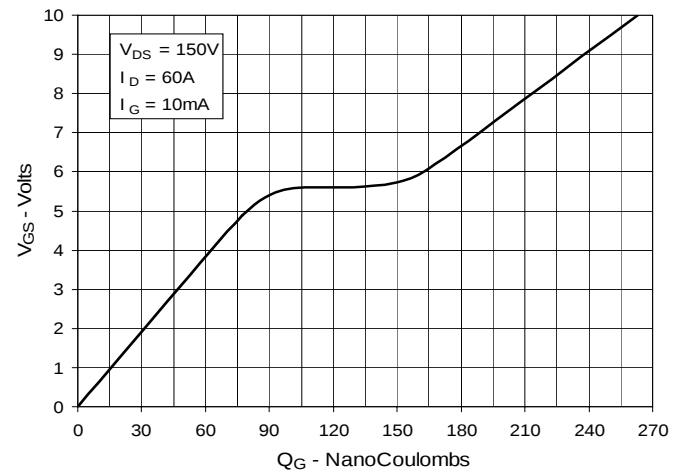


Fig. 11. Capacitance

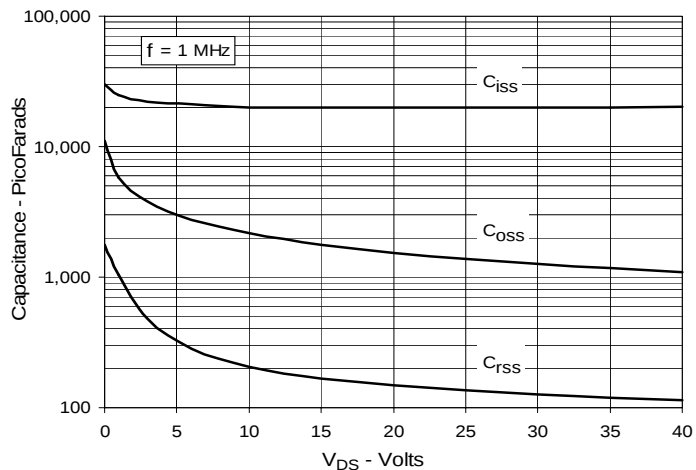


Fig. 12. Forward-Bias Safe Operating Area

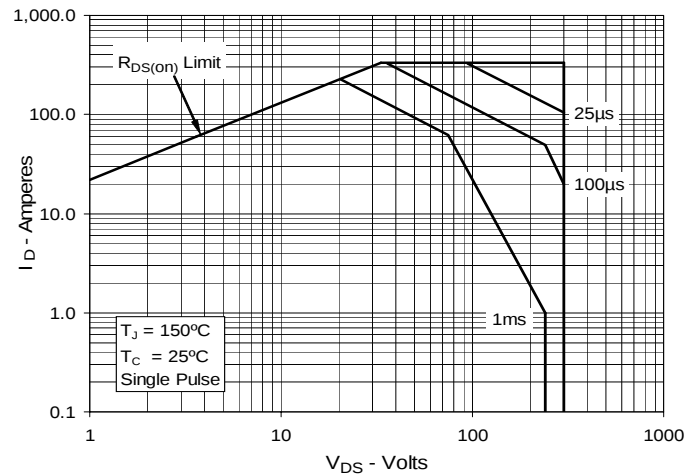
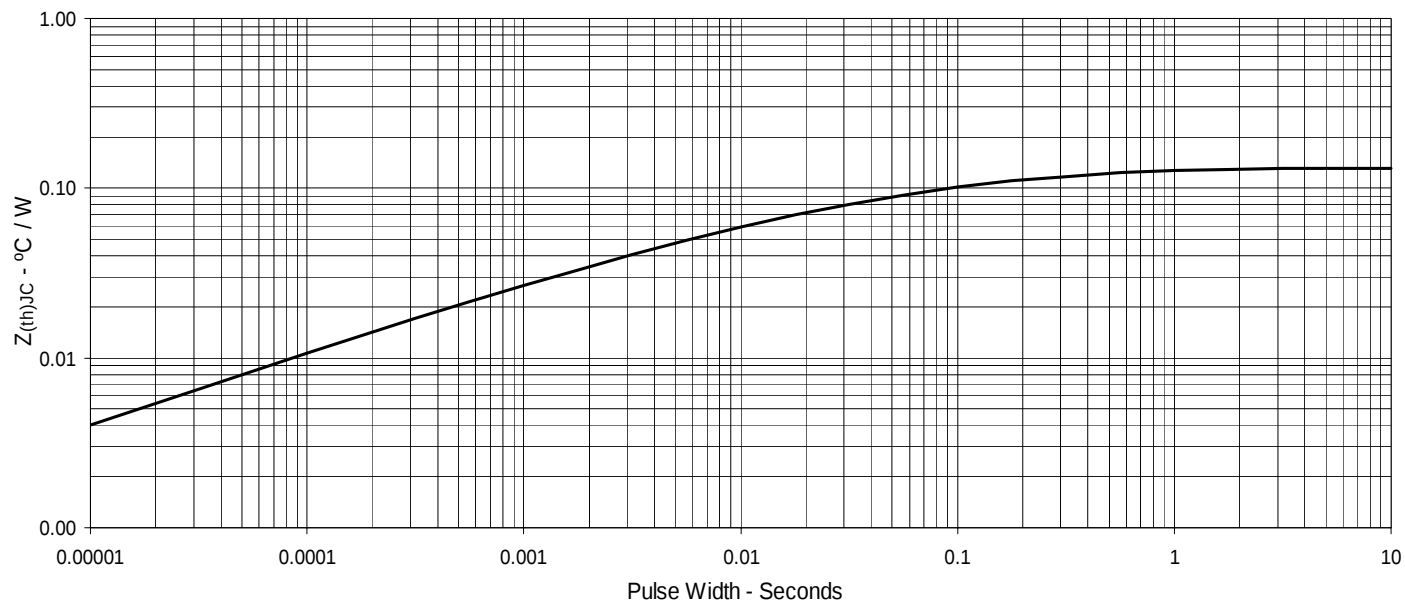


Fig. 13. Maximum Transient Thermal Impedance



# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[IXYS:](#)

[IXFK120N30T](#)